# HTH7G14S150H(B) 150W, 1.8 - 1400 MHz LDMOS Amplifier

Product datasheet

### **Description**

The HTH7G14S150H(B) is a unmatched discrete LDMOS Power Amplifier with 150W saturated output power covering frequency range from 1.8 - 1400 MHz.

#### **Features**

Operating Frequency Range: 1.8 - 1400 MHz

Operating Drain Voltage: 28-50V

Saturation Output Power: 150W

• Internally Unmatched device

 Excellent thermal stability due to low thermal resistance package

Enhanced robustness design without device degradation

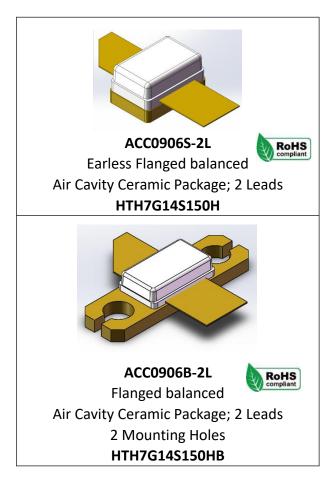
Internally integrated enhanced ESD design

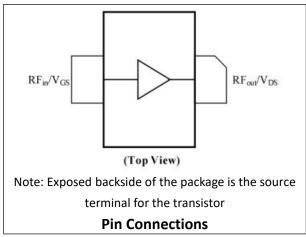
### **Applications**

- Industrial, scientific, medical (ISM)
  - Laser generation
  - o Plasma generation
  - Particle accelerators
  - o MRI, RF ablation and skin treatment
  - Industrial heating, welding and drying systems

### **Ordering Information**

Part Number	Description	
HTH7G14S150H(B)	Tray Package	
HTH7G14S150H(B)EVB	860 MHz EVB	





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### **Typical Performance**

#### **RF Characteristics (Pulsed CW)**

Freq (MHz)	P1dB (dBm)	P1dB (W)	Gain (dB)	Eff(%)@P3dB
860	52.0	158	21.5	56.0

Test conditions unless otherwise noted: 25 °C, VDD = +50Vdc, IDQ = 300mA, PW = 100us, DC = 10% test on HOTLO Application Board

### **Absolute Maximum Ratings**

Parameter	Range/Value	Unit
Drain voltage (VDSS)	-0.5 to +105	V
Gate voltage (V <sub>GS</sub> )	-5 to +10	V
Storage Temperature (Tstg)	-55 to +150	°C
Junction Temperature (T <sub>J</sub> )	-40 to +225	°C

# **Electrical Specification**

#### **DC Characteristics**

Parameter	Conditions	Min	Тур	Max	Unit
Breakdown Voltage V(BR)DSS	Vgs=0V, Ids=100uA	105	-	-	V
Gate-Source Threshold	\/ds=\/gs_lds=100uA	1.2	2.0	2.8	V
Voltage V <sub>GS(th)</sub>	Vds=Vgs, Ids=100uA	1.2	2.0	2.8	V
Drain Leakage Current loss	Vgs=0V, Vds=50V	-	-	10	uA
Gate Leakage Current Igss	Vgs=5V, Vds=0V	-	-	1	uA

#### **Load Mismatch Test**

Condition	Test Result
VSWR=20:1 at all Phase Angles, VDD = +50Vdc, IDQ=300mA, Pout = 150W,	No Device
PW = 200us, DC= 20%, freq@860 MHz	Degradation

#### **Thermal Information**

Parameter	Condition	Value (Typ)	Unit
Thormal Bosistanco	TFLANGE= 60°C, VDD = +50Vdc,		
Thermal Resistance	IDQ=300mA, Pout= 52 dBm (150W),	0.8	°C /W
Junction to Case (Rтн)	PW = 100us, DC= 10%, freq@860 MHz		

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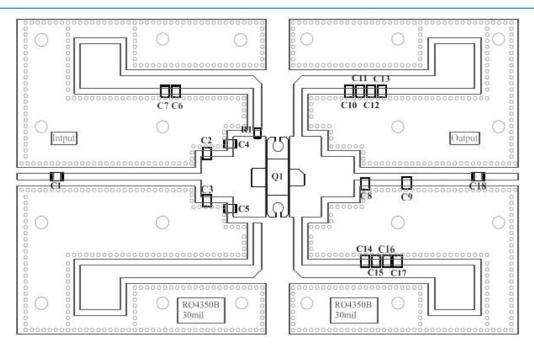


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#### HTH7G14S150H(B)

# 860 MHz Reference Design



**EVB Layout** 

# Bill of Materials (BoM) - HTH7G14S150H(B)

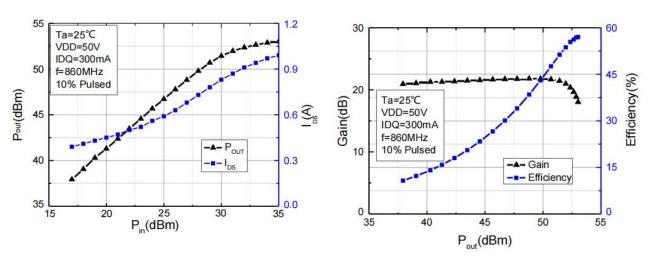
# 860 MHz Reference Design

Reference	Value	Description	Manufacturer	P/N
Q1	-	150W, 1.8 - 1400 MHz LDMOS PA	Holto	HTH7G14S150H(B)
C1, C6, C10, C14, C18	56pF	MLCC	ATC	ATC100B560JT500XT
C2	6.8pF	MLCC	ATC	ATC100B6R8JT500XT
C3	8.2pF	MLCC	ATC	ATC100B8R2JT500XT
C4, C5, C8	10pF	MLCC	ATC	ATC100B100JT500XT
C9	2.4pF	MLCC	ATC	ATC100B2R4JT500XT
C11, C15	10nF	MLCC	Murata	GR321AD72E103KW01D
C7, C12, C13, C16, C17	10uF	MLCC	Murata	GRM32EC72A106KE05
C19	10uF	MLCC	AVX	22201C106MAT2A
R1,	10Ω	Thick Film Resistor	YAGEO	RC0805FR-0710RL
PCB	Rogers4350B (er = 3.66), 30 mil (0.762 mm), 35 μm (1oz)			

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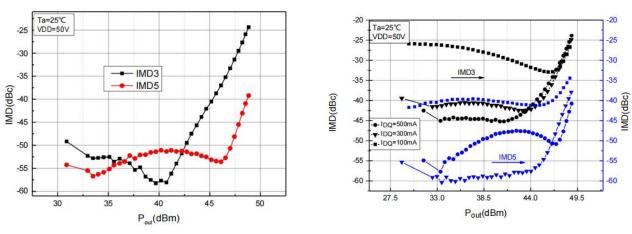
#### **Performance Plots**



#### Pulsed CW, Pout vs Pin

#### Pulsed CW, Gain and Efficiency vs Pout

Test conditions unless otherwise noted: 25 °C, VDD = +50dc, IDQ = 300mA, PW = 100us, DC = 10% test on HOTLO Application Board



Two Tone IMD vs Pout

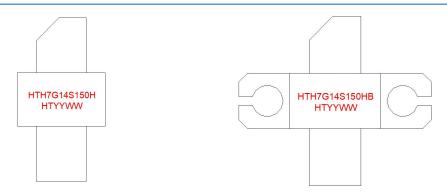
Two Tone IMD vs Pout @Idq's

Test conditions unless otherwise noted: 25 °C, VDD = +50Vdc, IDQ=300mA, Two tone Test, Carrier Spacing @600KHz test on HOTLO Application Board

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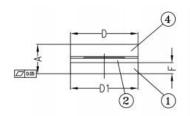
#### **Package Marking and Dimensions**

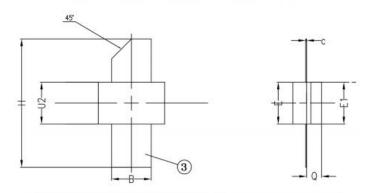


- Line1 (fixed): Device name in W/O
- Line2 (unfixed): HT+Date Code

This Marking SPEC only stipulates the content of Marking. For marking requirements such as font and size, please refer to the latest version of "Holto Product Printing Specification"

#### Marking





Symbol	Dimens	Dimensions In Millimeters		Dime	nsions In I	nches
M	Min.	Mon.	Max.	Min.	Mon.	Max.
Α	3.84	3.98	4.12	0.151	0.157	0.162
В	5.37	5.50	5.63	5.211	0.217	0.222
С	0.11	0.13	0.15	0.004	0.005	0.006
D	9.07	9.20	9.33	0.357	0.362	0.367
D1	9.07	9.20	9.33	0.357	0.362	0.367
E	5.67	5.80	5.93	0.223	0.228	0.233
E1	5.67	5.80	5.93	0.223	0.228	0.233
F	1.37	1.50	1.63	0.054	0.059	0.064
Н	17.30	17.80	18.30	0.681	0.701	0.720
Q	1.95	2.08	2.21	0.077	0.082	0.087
U2	5.67	5.80	5.93	0.223	0.228	0.233

**Package Dimensions** 

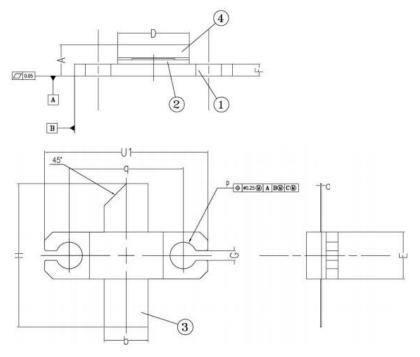
ACC0906S-4L Earless Flanged Air Cavity Ceramic Package; 2 Leads

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	Dimesions in Milimeters		D	imesions in Inch	es	
Symbol	Min.	Mon.	Max.	Min.	Mon.	Max.
A	3.84	3.98	4,12	0.151	0.157	0.162
b	5.37	5.50	5.63	5.211	0.217	0.222
c	0.11	0.13	0.15	0.004	0.005	0.006
D	9.07	9.20	9.33	0.357	0.362	0.367
E	5.67	5.80	5.93	0.223	0.228	0.233
F	1.37	1.50	1.63	0.054	0.059	0.064
G	1.07	1.20	1.33	0.042	0.047	0.052
Н	17.30	17.80	18.30	0.681	0.701	0.720
p	3.05	3.3	3.55	0.120	0.130	0.140
q	14.07	14,20	14.33	0.554	0.559	0.564
U1	20.17	20.30	20.43	0.794	0.799	0.804

**Package Dimensions** 

ACC0906B-2L Flanged balanced Air Cavity Ceramic Package; 2 Leads; 2 Mounting Holes

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# **Tape and Reel Information**

Package Type	Qty/Tray(pcs)	Qty/Box(pcs)
ACC0906	30	300



**Packaging Descriptions** 

# **Handling Precautions**

Parameter	Grade
Moisture Sensitivity Level MSL	3

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	Class 1B	JESD22-A114
ESD – Human Body Model (MM)	Class A	EIA/JESD22-A115
ESD – Charged Device Model (CDM)	Class III	JESD22-C101



#### **RoHS Compliance**

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

#### **Datasheet Status**

Document status	Product status	Definition
Objective Datasheet	Design simulation	Product objective specification
Preliminary Datasheet	Customer sample	Engineering samples and first test results
Product Datasheet	Mass production	Final product specification

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### **Abbreviations**

Acronym	Definition
LDMOS	Laterally-Diffused Metal-Oxide Semiconductor
CW	Continuous Waveform

# **Revision history**

Document ID	Datasheet Status	Release Date	Revision Version
Rev 2.2	Product	March 2023	New format based on English version datasheet
Rev 2.3	Product	Sept. 2023	Update TBD information
Rev 2.4	Product	March 2024	Version released after re review

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#### **Contact Information**

For the latest specifications, additional product information, worldwide sales and distribution locations and information about HOTLO:

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